

Operational Amplifier Specifications

Gain, Frequency Response, and Dynamic Limitations

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Spring 2026

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Op-Amp
Specifications

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Other Important
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Summary

Why Study Op-Amp Specifications?

Ideal vs. Real Op-Amps:

- 😊 **Ideal:** Simple analysis, perfect behavior
- 😐 **Real:** Practical limitations exist
- 😞 Ignoring specs → circuit failure!

Key Questions:

- What gain can I actually achieve?
- How fast can my circuit respond?
- What frequencies can I amplify?
- What errors will appear in my output?

Real-World Applications:

- Audio amplifiers (20 Hz - 20 kHz)
- Active filters
- Analog sensor systems
- Control systems

Lecture Objectives

- Understand DC and AC specifications
- Analyze frequency response limitations
- Apply slew rate constraints
- Select appropriate op-amps for applications

Overview of Key Specifications

Category	Parameter	Typical Value (741)
DC Specs	Open-loop gain A_0	200,000 (106 dB)
	Input offset voltage V_{OS}	1–5 mV
	Input bias current I_B	80 nA
AC Specs	Gain-bandwidth product (GBW)	1 MHz
	Unity-gain frequency f_t	1 MHz
	Phase margin	60°
Dynamic	Slew rate (SR)	0.5 V/ μ s
	Full-power bandwidth	8 kHz
Other	CMRR	90 dB
	PSRR	80 dB

Note

These are **typical values for the 741 op-amp**. Modern op-amps offer better performance

Open-Loop Gain: Finite, Not Infinite

Open-Loop Gain A_0 :

$$v_{out} = A_0(v_+ - v_-)$$

Real vs. Ideal:

- **Ideal:** $A_0 = \infty$
- **Real:** $A_0 = 10^5 - 10^6$ (100-120 dB)

Typical Values:

- 741: $A_0 \approx 200,000$ (106 dB)
- LM324: $A_0 \approx 100,000$ (100 dB)
- TL081: $A_0 \approx 200,000$ (106 dB)
- OP07: $A_0 \approx 1,000,000$ (120 dB)

Impact on Closed-Loop Gain:

For inverting amplifier with ideal gain:

$$G_{actual} = G_{ideal} \cdot \frac{A_0}{A_0 + 1 + |G_{ideal}|}$$

Example: $G_{ideal} = -100$, $A_0 = 100,000$

$$G_{actual} = -100 \cdot \frac{100,000}{100,101} \approx -99.9$$

Design Rule

For accurate gain, choose op-amp with:

$$A_0 \gg |G_{closed-loop}|$$

Rule of thumb: $A_0 > 100 \times |G|$

Input Referred Offset Voltage

Definition:

Input offset voltage V_{OS} is the **differential voltage** required at the inputs to force $v_{out} = 0$.

Physical Cause:

- ☹ Transistor mismatches inside IC
- ☹ Manufacturing variations

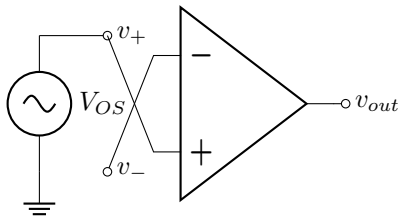


Figure 1: Offset voltage model

Key Characteristics:

- ☹ **Sample-to-sample variation:** Each IC has different V_{OS}
- ☹ **Not predictable:** Cannot know exact value without measurement
- 😊 **Datasheet specifies range:** Typical and maximum values given
- 😊 **Feedback helps:** Not critical when op-amp is in negative feedback

Effect in Non-Inverting Amplifier:

$$V_{out,offset} = V_{OS} \cdot G$$

Example: $V_{OS} = 2 \text{ mV}$, $G = 100$

$$V_{out,offset} = 2 \text{ mV} \times 100 = 200 \text{ mV}$$

Open-Loop Frequency Response

Single-Pole Rolloff:

Most op-amps have internally compensated frequency response:

$$A(f) = \frac{A_0}{1 + jf/f_b}$$

where:

- A_0 = DC open-loop gain
- f_b = break frequency (3-dB point)

Magnitude Approximation:

- $f < f_b$: $|A| \approx A_0$ (flat)
- $f > f_b$: $|A| \approx A_0 f_b / f$ (-20 dB/decade)

Bode Plot - Open Loop:

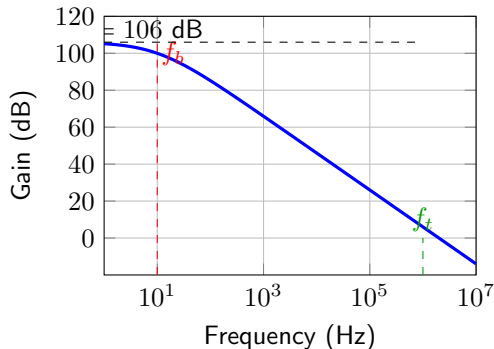


Figure 2: Typical 741 open-loop response

Gain-Bandwidth Product

Unity-Gain Frequency f_t :

Frequency where $|A(f_t)| = 1$ (0 dB):

$$f_t = A_0 \cdot f_b$$

Gain-Bandwidth Product (GBW):

For frequencies $f \gg f_b$:

$$|A(f)| \cdot f = A_0 \cdot f_b = f_t = \text{constant}$$

Example - 741:

- $A_0 = 200,000$ (106 dB)
- $f_b = 5$ Hz
- $f_t = 200,000 \times 5 = 1$ MHz
- $GBW = 1$ MHz

Closed-Loop Bandwidth:

For closed-loop gain G :

$$f_{-3dB} = \frac{f_t}{G}$$

Gain-Bandwidth Tradeoff

Higher gain \rightarrow lower bandwidth!

$$G \times BW = f_t = \text{constant}$$

Examples (741, $f_t = 1$ MHz):

Gain	Bandwidth
1	1 MHz

Closed-Loop Frequency Response

Non-Inverting Amplifier:

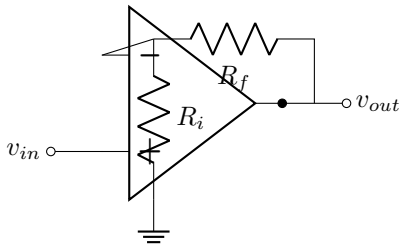


Figure 3: Non-inverting amplifier

Ideal Gain:

$$G = 1 + \frac{R_f}{R_i}$$

Frequency Response for Different Gains:

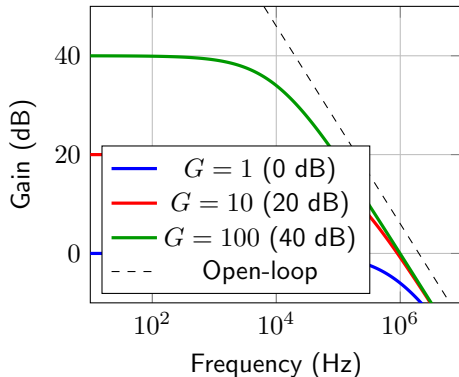


Figure 4: Closed-loop response for various gains

Phase Margin and Stability

Phase Margin (PM):

Amount of additional phase shift (beyond -180°) at unity-gain frequency before instability:

$$PM = 180^\circ + \phi(f_t)$$

Stability Criteria:

- $PM > 45^\circ$: stable, good damping
- $PM \approx 60^\circ$: optimal (typical design)
- $PM < 30^\circ$: marginal, may oscillate
- $PM \leq 0^\circ$: unstable

Compensation

Bode Plot - Phase Response:

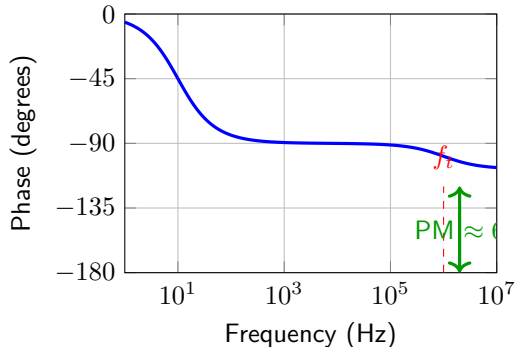


Figure 5: Phase response showing phase margin

Small Signal AC Model

Frequency-Dependent Model:

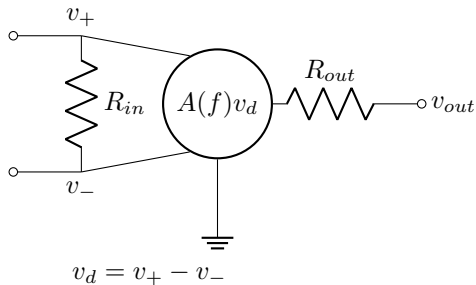


Figure 6: Small-signal AC model

Frequency-Dependent Gain:

Typical Parameter Values:

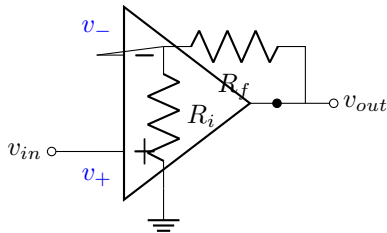
Parameter	Typical (741)
R_{in}	2 M Ω
R_{out}	75 Ω
A_0	200,000 V/V
f_b	5 Hz
f_t	1 MHz

Analysis Steps:

- 1 Replace op-amp with AC model
- 2 Apply frequency-dependent $A(f)$
- 3 Solve for transfer function

Closed-Loop Gain Derivation

Non-Inverting Amplifier Analysis:



Feedback factor:

$$\beta = \frac{R_i}{R_i + R_f}$$

Ideal closed-loop gain:

Actual Closed-Loop Gain:

With finite open-loop gain $A(f)$:

$$G(f) = \frac{v_{out}}{v_{in}} = \frac{A(f)}{1 + A(f)\beta}$$

Substituting $A(f) = A_0/(1 + jf/f_b)$:

$$G(f) = \frac{G_{ideal}}{1 + jf/f_{-3dB}}$$

where the 3-dB frequency is:

$$f_{-3dB} = f_b(1 + A_0\beta) \approx A_0\beta f_b = \frac{f_t}{G_{ideal}}$$

Example: Bandwidth Calculation

Problem: Design a non-inverting amplifier with gain of 20 using a 741 op-amp ($f_t = 1$ MHz). Find the bandwidth.

Given:

- Desired gain: $G = 20$
- Op-amp: 741 with $f_t = 1$ MHz

Design:

$$G = 1 + \frac{R_f}{R_i} = 20$$

$$\frac{R_f}{R_i} = 19$$

Choose $R_i = 1 \text{ k}\Omega$, then:

Bandwidth:

$$f_{-3dB} = \frac{f_t}{G} = \frac{1 \text{ MHz}}{20} = 50 \text{ kHz}$$

Verification:

$$G \times BW = 20 \times 50 \text{ kHz} = 1 \text{ MHz} = f_t \quad \checkmark$$

Conclusion

The amplifier will have a flat gain of 20 (26 dB) from DC up to 50 kHz, then roll off at

Slew Rate: Large Signal Limitation

Definition:

Slew Rate (SR) is the maximum rate of change of the output voltage:

$$SR = \left| \frac{dv_{out}}{dt} \right|_{max} \quad (V/\mu s)$$

Physical Cause:

- Limited internal charging current
- Compensation capacitor charging time
- Transistor saturation

Typical Values:

- 741: $SR = 0.5 \text{ V}/\mu s$
- TL081: $SR = 13 \text{ V}/\mu s$

Slew Rate Limiting:

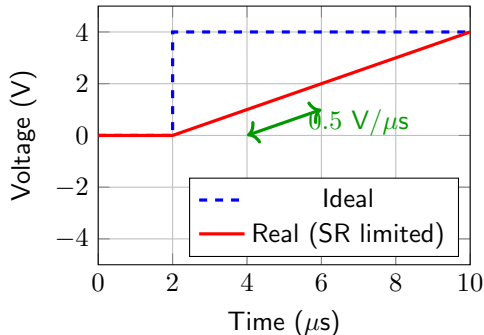


Figure 7: Step response with slew-rate limiting

Slew Rate and Sinusoidal Signals

Sinusoidal Output:

For $v_{out}(t) = V_p \sin(2\pi ft)$:

$$\frac{dv_{out}}{dt} = 2\pi f V_p \cos(2\pi ft)$$

Maximum slope:

$$\left| \frac{dv_{out}}{dt} \right|_{max} = 2\pi f V_p$$

No Distortion Condition:

$$2\pi f V_p \leq SR$$

Full-Power Bandwidth:

Slew-Rate Distortion:

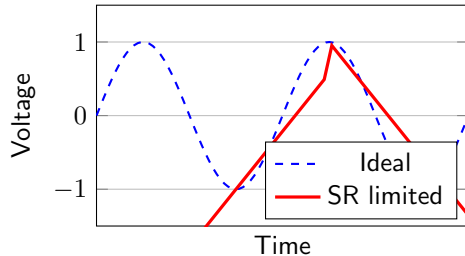


Figure 8: Slew-rate distortion of sine wave

Example - 741:

$SR = 0.5 \text{ V}/\mu\text{s}$, $V_p = 10 \text{ V}$:

$$0.5 \times 10^6$$

Full-Power Bandwidth vs. Small-Signal Bandwidth

Two Different Bandwidths:

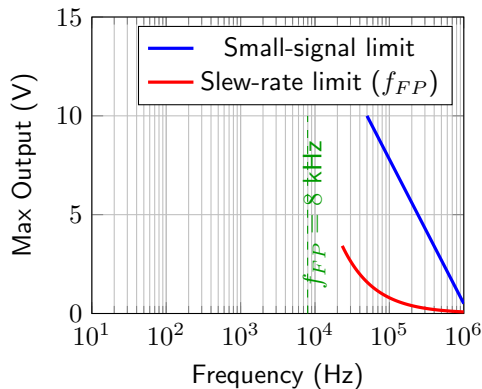
1. Small-Signal Bandwidth f_{-3dB} :

- Determined by GBW product
- $f_{-3dB} = f_t / G$
- Valid for small output swings

2. Full-Power Bandwidth f_{FP} :

- Determined by slew rate
- $f_{FP} = SR / (2\pi V_p)$
- Valid for large output swings

Comparison Plot:



Design Rule

Actual usable bandwidth:

Figure 9: 741: $G = 1$, $SR = 0.5 \text{ V}/\mu\text{s}$, $f_t = 1$

Settling Time and Rise Time

Settling Time t_s :

Time for output to reach and stay within a specified error band (typically $\pm 0.1\%$ or $\pm 0.01\%$) of final value.

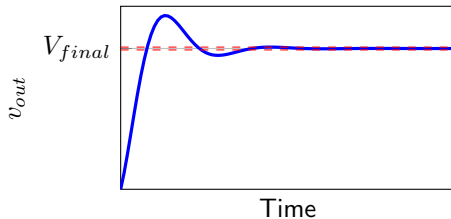


Figure 10: Settling time to $\pm 1\%$ band

Rise Time t_r :

Time for output to rise from 10

Relationship to Bandwidth:

$$t_r \approx \frac{0.35}{f_{-3dB}}$$

Example - Unity-Gain Buffer (741):

$f_{-3dB} = f_t = 1 \text{ MHz}$:

$$t_r = \frac{0.35}{1 \text{ MHz}} = 0.35 \mu\text{s} = 350 \text{ ns}$$

Common-Mode Rejection Ratio (CMRR)

Definition:

Ratio of differential gain to common-mode gain:

$$CMRR = \frac{A_d}{A_{cm}} = \frac{|A(v_+ - v_-)|}{|A(v_{cm})|}$$

Usually expressed in dB:

$$CMRR_{dB} = 20 \log_{10}(CMRR)$$

Typical Values:

- 741: $CMRR = 90 \text{ dB}$
- OP07: $CMRR = 110 \text{ dB}$
- TL081: $CMRR = 86 \text{ dB}$

Effect of Finite CMRR:

Common-mode input v_{cm} appears as:

$$v_{error} = \frac{v_{cm}}{CMRR}$$

Example:

$v_{cm} = 5 \text{ V}$, $CMRR = 90 \text{ dB} = 31,623$:

$$v_{error} = \frac{5}{31,623} = 158 \mu\text{V}$$

Frequency Dependence:



Power Supply Rejection Ratio (PSRR)

Definition:

Measure of how well op-amp rejects power supply variations:

$$PSRR = \frac{\Delta V_{supply}}{\Delta V_{os}}$$

Usually expressed in dB:

$$PSRR_{dB} = 20 \log_{10}(PSRR)$$

Typical Values:

- 741: PSRR = 80 dB (+ supply)
- OP07: PSRR = 110 dB
- TL081: PSRR = 80 dB

Effect of Finite PSRR:

Ripple on supply ΔV_{supply} appears as offset:

$$V_{os,induced} = \frac{\Delta V_{supply}}{PSRR}$$

Example:

100 mV ripple, PSRR = 80 dB = 10,000:

$$V_{os,induced} = \frac{100 \text{ mV}}{10,000} = 10 \mu\text{V}$$

Power Supply Design

For low-noise applications:

Input and Output Impedances (Real)

Input Impedance:

Differential input impedance:

- BJT input (741): $R_{in} \approx 2 \text{ M}\Omega$
- JFET input (TL081): $R_{in} \approx 10^{12} \Omega$
- CMOS input: $R_{in} \approx 10^{13} \Omega$

Common-mode input impedance:

- Usually much higher
- Typically in $\text{G}\Omega$ range

Effect on Source Loading

For source impedance R_s :

$$\frac{v_{in,actual}}{v_{in,theoretical}} = \frac{R_{in}}{R_{in} + R_s}$$

Output Impedance:

Open-loop: $R_{out} \approx 50 - 100 \Omega$ (typical)

Closed-loop (with feedback):

$$R_{out,CL} = \frac{R_{out}}{1 + A\beta}$$

For large loop gain $A\beta$:

$$R_{out,CL} \approx \frac{R_{out}}{A\beta} \ll 1 \Omega$$

Maximum Output Current:

- 741: $I_{out,max} \approx \pm 25 \text{ mA}$
- TL081: $I_{out,max} \approx \pm 20 \text{ mA}$

Output Voltage Swing Limitations

Output Swing vs. Supply:

Output cannot reach supply rails:

$$V_{out,min} = -V_{EE} + V_{sat}$$

$$V_{out,max} = +V_{CC} - V_{sat}$$

where V_{sat} is the saturation voltage.

Typical Saturation Voltages:

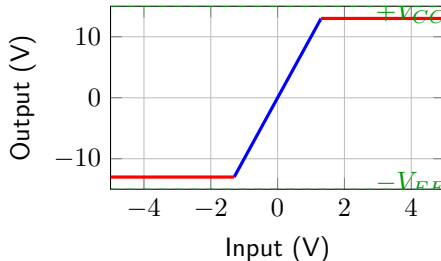
- 741: $V_{sat} \approx 2 \text{ V}$
- TL081: $V_{sat} \approx 1.5 \text{ V}$
- Rail-to-rail op-amps: $V_{sat} \approx 50 \text{ mV}$

Example - 741 with $\pm 15 \text{ V}$ supplies:

$$V_{out,max} = +15 - 2 = +13 \text{ V}$$

$$V_{out,min} = -15 + 2 = -13 \text{ V}$$

Output swing: $\pm 13 \text{ V}$ (not $\pm 15 \text{ V}$!)



Choosing the Right Op-Amp

Application	Key Specs	Recommended
General purpose	Low cost, moderate specs	741, LM324, TL081
Precision DC amplifier	Low V_{OS} , low drift	OP07, OP177, LT1013
High-speed	High SR, high f_t	LM318, THS4031, AD8099
Audio	Low noise, good THD	NE5532, OPA2134, LM4562
Low power	Low supply current	TLV2371, LMC7101, MAX4236
High input impedance	JFET/CMOS input	TL081, CA3140, LMC6482
Single supply	Rail-to-rail I/O	LM358, LMV321, MCP6002
Instrumentation	High CMRR, low noise	INA128, AD620, LT1167

Selection Process

Comparison of Common Op-Amps

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Summary

Part	A_0 (dB)	f_t (MHz)	SR (V/ μ s)	V_{OS} (mV)	I_B	Type
741	106	1	0.5	1-5	80 nA	BJT, general
LM324	100	1	0.5	2-7	45 nA	BJT, quad, single supply
TL081	106	3	13	3-15	50 pA	JFET, high Z_{in}
OP07	120	0.6	0.3	0.025-0.075	2 nA	BJT, precision
OP177	126	0.6	0.3	0.01-0.025	0.5 nA	BJT, ultra-precision
LM318	100	15	70	2-10	150 nA	BJT, high-speed
THS4031	110	100	370	0.5	10 μ A	BJT, very high-speed
NE5532	100	10	9	0.5-4	200 nA	BJT, low-noise audio
LMC6482	106	1.5	1.1	0.4-1.5	2 fA	CMOS, rail-to-rail
CA3140	100	4.5	9	2-15	10 pA	BiMOS, high Z_{in}

Design Tradeoffs

- **Precision vs. Speed:** High precision op-amps often have lower bandwidth
- **Input Type:** BJT (low V_{OS}), JFET (low I_B), CMOS (ultra-low I_B)
- **Power vs. Performance:** Lower power \rightarrow lower speed/drive capability

Summary: Real Op-Amp Specifications

DC Specifications:

- Open-loop gain: A_0 (finite, not infinite)
- Input offset voltage: V_{OS}
- Input bias current: I_B
- Input offset current: I_{OS}
- Temperature drift: dV_{OS}/dT , dI_B/dT

Frequency Response:

- Open-loop gain:
 $A(f) = A_0/(1 + jf/f_b)$
- Unity-gain frequency: f_t
- Gain-bandwidth product:
 $G \times BW = f_t$

Dynamic Limitations:

- Slew rate: SR ($V/\mu s$)
- Full-power bandwidth:
 $f_{FP} = SR/(2\pi V_p)$
- Settling time, rise time
- Output swing limitations

Other Specifications:

- CMRR (common-mode rejection)
- PSRR (power supply rejection)
- Input impedance: R_{in}
- Output impedance: R_{out}
- Maximum output current

Key Formulas Reference

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Parameter	Formula
Open-loop gain (AC)	$A(f) = \frac{A_0}{1 + jf/f_b}$
Unity-gain frequency	$f_t = A_0 \cdot f_b$
Closed-loop bandwidth	$f_{-3dB} = \frac{f_t}{G_{closed}}$
Gain-bandwidth product	$G \times BW = f_t = \text{constant}$
Full-power bandwidth	$f_{FP} = \frac{SR}{2\pi V_p}$
Rise time	$t_r \approx \frac{0.35}{f_{-3dB}}$
Max slew rate	$SR = \left \frac{dv_{out}}{dt} \right _{max}$

Practice Problem 1

Given: A non-inverting amplifier using a 741 op-amp ($f_t = 1 \text{ MHz}$, $SR = 0.5 \text{ V}/\mu\text{s}$) with $R_i = 1 \text{ k}\Omega$ and $R_f = 99 \text{ k}\Omega$.

Find:

- (a) The ideal closed-loop gain
- (b) The small-signal bandwidth
- (c) The maximum output voltage swing at 10 kHz without slew-rate distortion
- (d) The full-power bandwidth for $V_{out,p} = 10 \text{ V}$

Hints:

- $G = 1 + R_f/R_i$
- $f_{-3dB} = f_t/G$
- $SR = 2\pi f V_p$ (for undistorted sine wave)
- $f_{FP} = SR/(2\pi V_p)$

Practice Problem 1 Solution

Given: $R_i = 1 \text{ k}\Omega$, $R_f = 99 \text{ k}\Omega$, $f_t = 1 \text{ MHz}$, $SR = 0.5 \text{ V}/\mu\text{s}$

(a) Closed-loop gain:

$$G = 1 + \frac{R_f}{R_i} = 1 + \frac{99 \text{ k}\Omega}{1 \text{ k}\Omega} = 1 + 99 = 100$$

(b) Small-signal bandwidth:

$$f_{-3dB} = \frac{f_t}{G} = \frac{1 \text{ MHz}}{100} = 10 \text{ kHz}$$

(c) Max output at 10 kHz:

For no slew-rate distortion: $SR = 2\pi f V_p$

$$V_p = \frac{SR}{2\pi f} = \frac{0.5 \times 10^6 \text{ V/s}}{2\pi \times 10,000 \text{ Hz}} = 7.96 \text{ V}$$

(d) Full-power bandwidth for 10 V:

$$f_{FP} = \frac{SR}{2\pi V_p} = \frac{0.5 \times 10^6}{2\pi \times 10} = 7.96 \text{ kHz}$$

Practice Problem 2

Given: An inverting amplifier with gain of -50 using an OP07 op-amp:

- $A_0 = 1,000,000$ (120 dB)
- $V_{OS} = 50 \mu\text{V}$ at 25°C
- $dV_{OS}/dT = 0.3 \mu\text{V}/^\circ\text{C}$
- $I_B = 2 \text{ nA}$
- $R_i = 10 \text{ k}\Omega$

Find:

- (a) R_f for the desired gain
- (b) Output offset voltage due to V_{OS} at 25°C
- (c) Additional output error due to I_B (worst case)
- (d) Total output offset at 70°C

Practice Problem 2 Solution

(a) Feedback resistor:

For inverting amplifier: $G = -R_f/R_i = -50$

$$R_f = 50 \times R_i = 50 \times 10 \text{ k}\Omega = 500 \text{ k}\Omega$$

(b) Output offset at 25°C:

Inverting config acts like non-inverting for offset: $|G| = 1 + R_f/R_i = 51$

$$V_{out,offset} = V_{OS} \times 51 = 50 \mu\text{V} \times 51 = 2.55 \text{ mV}$$

(c) Error from bias current:

$$V_{error,IB} = I_B \times R_f = 2 \text{ nA} \times 500 \text{ k}\Omega = 1 \text{ mV}$$

(d) Total offset at 70°C:

$$\Delta T = 70 - 25 = 45^\circ\text{C}$$

$$V_{OS,70} = 50 \mu\text{V} + (0.3 \mu\text{V}/^\circ\text{C}) \times 45^\circ\text{C} = 63.5 \mu\text{V}$$

$$V_{out,total} = (63.5 \mu\text{V} \times 51) + 1 \text{ mV} = 3.24 \text{ mV} + 1 \text{ mV} = 4.24 \text{ mV}$$

Practice Problem 3

Scenario: You need to amplify a 1 kHz sine wave from 100 mV peak to 5 V peak with less than 1% distortion.

Given two op-amp options:

- **Option A:** $f_t = 1 \text{ MHz}$, $\text{SR} = 0.5 \text{ V}/\mu\text{s}$
- **Option B:** $f_t = 10 \text{ MHz}$, $\text{SR} = 10 \text{ V}/\mu\text{s}$

Questions:

- What gain is required?
- Is Option A suitable? Check both bandwidth and slew rate.
- Is Option B suitable? Check both bandwidth and slew rate.
- Which would you choose and why?

Practice Problem 3 Solution

(a) Required gain:

$$G = \frac{V_{out,p}}{V_{in,p}} = \frac{5 \text{ V}}{0.1 \text{ V}} = 50$$

(b) Option A - Check:

Bandwidth: $f_{-3dB} = f_t/G = 1 \text{ MHz}/50 = 20 \text{ kHz} > 1 \text{ kHz}$ 😊

Slew rate: Required $SR = 2\pi f V_p = 2\pi \times 1000 \times 5 = 31.4 \text{ kV/s} = 0.031 \text{ V}/\mu\text{s}$

Available $SR = 0.5 \text{ V}/\mu\text{s} > 0.031 \text{ V}/\mu\text{s}$ 😊

Option A is suitable!

(c) Option B - Check:

Bandwidth: $f_{-3dB} = 10 \text{ MHz}/50 = 200 \text{ kHz} \gg 1 \text{ kHz}$ 😊

Slew rate: Available $= 10 \text{ V}/\mu\text{s} \gg 0.031 \text{ V}/\mu\text{s}$ 😊

Option B is also suitable (with margin)!

(d) Recommendation: Choose **Option A** — adequate performance at likely lower cost. Option B is over-specified for this application.